

Coulomb Charging at Large Conduction

Xiaohui Wang and Hermann Grabert

Fakultät für Physik, Universität Freiburg, Hermann-Herder-Straße 3, 79104 Freiburg, Germany
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We discuss the suppression of Coulomb charging effects on a small metallic island coupled to an electrode by a tunnel junction. At high temperatures the quantum corrections to the classical charging energy $E_c = e^2/2C$, where C is the island capacitance, are evaluated. At low temperatures the large quantum fluctuations of the island charge cause a strong reduction of the effective E_c which is determined explicitly in the limit of a large tunneling conductance.

In recent years Coulomb blockade effects in metallic nanostructures have been studied extensively both theoretically and experimentally¹. These effects arise in systems with small metallic islands separated by tunnel barriers. For the case of weak tunneling addressed mostly so far² the transfer of charges can be described in terms of a tunneling Hamiltonian treated perturbatively. On the other hand, for strong tunneling one expects a washout of charging effects by large quantum fluctuations of the charge. For a quantum dot coupled by a point contact to a lead electrode, the dependence of charging effects on the transmission coefficient was studied in recent work³. However, in this case there are only few transport channels.

The behavior of metallic tunnel junctions with many channels can conveniently be described by a path integral over fluctuations of the phase conjugate to the island charge⁴. Based on this approach the suppression of Coulomb effects was studied earlier by several authors^{5–8}. Most of these papers have considered single junctions while it became clear later⁹ that in this case charging effects are usually suppressed by the coupling to electromagnetic modes. On the other hand, charge quantization on small metallic islands is predominantly affected by fluctuations of charge carriers across adjacent tunnel junctions^{10–14}.

The simplest device displaying these effects is the so-called single electron box (SEB) which is formed by a metallic island between by a tunnel junction and a gate capacitor (cf. Fig. 1). The external electrodes are biased by a voltage source¹⁵. Recently, Falci *et al.*⁸ have examined the low temperature behavior of the SEB by means of renormalization group techniques. While powerful in predicting the main parameter dependence of the effective charging energy in the low temperature range, this method does not allow for a determination of the precise relation between low temperature parameters and quantities measurable in the classical regime. On the other hand, experiments cover both the range of classical and quantum mechanical charge fluctuations and one would like to examine the low temperature behavior of devices in terms of parameters measured in the classical regime.

In this article we present a new method to evaluate the path integral in phase representation. At low temperatures the path integral is dominated by “sluggon” trajectories describing phase creep by 2π across the junction. The contribution of these trajectories can be evaluated explicitly in the limit of low temperatures and large tunneling conductance. As a main result we find that the dominant effect of charge fluctuations can be absorbed in an effective charging energy.

We start from the partition function of the SEB at inverse temperature $\beta = 1/k_B T$ which may be written as

$$Z = \int D[\varphi] e^{-S_{\text{Box}}[\varphi]},$$

where the integral is over all paths of the phase $\varphi(\tau)$ in the interval $-\beta/2 \leq \tau \leq \beta/2$ with $\varphi(\beta/2) = \varphi(-\beta/2)$ modulus 2π . The action $S_{\text{Box}}[\varphi] = S_c[\varphi] + S_t[\varphi]$ contains two parts describing charging of the island and tunneling across the junction. The effect of the Coulomb energy is contained in

$$S_c[\varphi] = \int_{-\beta/2}^{\beta/2} d\tau \left[\frac{1}{4E_c} (\dot{\varphi} + 2in_{\text{ex}}E_c)^2 + E_c n_{\text{ex}}^2 \right]$$

where $E_c = e^2/2C$ is the single electron charging energy, in which the island capacitance C is the sum of the capacitance C_t of the tunnel junction and the gate capacitance C_g . $n_{\text{ex}} = C_g U/e$ is a dimensionless measure of the voltage U applied via the gate capacitance (cf. Fig. 1). The second part of the action⁴

$$S_t[\varphi] = 2 \int_{-\beta/2}^{\beta/2} d\tau \int_{-\beta/2}^{\beta/2} d\tau' \alpha(\tau - \tau') \sin^2 \left[\frac{\varphi(\tau) - \varphi(\tau')}{2} \right]$$

describes tunneling. The Fourier transform of $\alpha(\tau)$ reads $\alpha_l = -\alpha_t |\omega_l|/4\pi$ for $|\omega_l| \ll D$ where the $\omega_l = 2\pi l/\beta$ are Matsubara frequencies, D is the electronic bandwidth, and $\alpha_t = R_K/R_t$ is the dimensionless conductance of the junction, where R_t is the tunneling resistance and $R_K = h/e^2$ the von-Klitzing resistance.

Since the action is a periodic function of φ with period 2π , the partition function may be written as a sum over “winding numbers”,

$$Z = \sum_{k=-\infty}^{\infty} e^{2\pi i k n_{\text{ex}}} Z_k.$$

Here

$$Z_k = \int_{\varphi(\beta/2)=\varphi(-\beta/2)+2\pi k} D[\varphi] e^{-S[\varphi]}$$

where the action $S[\varphi] = S_0[\varphi] + S_t[\varphi]$, with $S_0[\varphi] = \int_{-\beta/2}^{\beta/2} d\tau \dot{\varphi}^2/4E_c$.

Due to the nonlinear, nonlocal interactions described by $S_t[\varphi]$, the partition function cannot be evaluated exactly. Here we shall employ semiclassical methods. The classical paths (from $\delta S[\varphi] = 0$) satisfy

$$\ddot{\varphi} - 4E_c \int_{-\beta/2}^{\beta/2} d\tau' \alpha(\tau - \tau') \sin[\varphi(\tau) - \varphi(\tau')] = 0, \quad (1)$$

and the boundary condition for winding number k reads $\varphi(\beta/2) = \varphi(-\beta/2) + 2\pi k$. A trivial solution of this equation is^{7,8}

$$\varphi_{\text{cl}}^{(k)}(\tau) = \varphi(-\beta/2) + \omega_k(\tau + \beta/2)$$

with the classical action

$$S_{\text{cl}}^{(k)} = \frac{\pi^2 k^2}{\beta E_c} + |k| \frac{\alpha_t}{2}.$$

For an arbitrary path $\varphi(\tau) = \varphi_{\text{cl}}^{(k)}(\tau) + \theta(\tau)$ of winding number k fluctuating about the classical solution, the second order variational action reads

$$\delta^2 S^{(k)} = \int_{-\beta/2}^{\beta/2} d\tau \frac{\dot{\theta}^2}{4E_c} + \frac{1}{2} \int_{-\beta/2}^{\beta/2} d\tau \int_{-\beta/2}^{\beta/2} d\tau' \alpha(\tau - \tau') \cos[\omega_k(\tau - \tau')] [\theta(\tau) - \theta(\tau')]^2.$$

In terms of the Fourier transform $\theta_l = \theta'_l + i\theta''_l$, the action takes the form

$$\delta^2 S^{(k)} = \frac{1}{\beta} \sum_{l=1}^{\infty} \lambda_l^{(k)} (\theta'_l{}^2 + \theta''_l{}^2),$$

where for $l \ll \beta D$

$$\lambda_l^{(k)} = \frac{\omega_l^2}{2E_c} + \Theta(l - |k|) \frac{\alpha_t \omega_{l-|k|}}{2\pi}.$$

For very large l the eigenvalues approach $\omega_l^2/2E_c$ independent of k . Upon normalization of the path integral the large l contributions cancel. It is now straightforward to show that

$$Z = Z_0 \left[1 + 2 \sum_{k=1}^{\infty} C_k \cos(2\pi k n_{\text{ex}}) \right], \quad (2)$$

where Z_0 is the contribution of paths with winding number 0 which is independent of n_{ex} and

$$C_k = \frac{\Gamma(1+k_+) \Gamma(1+k_-)}{\Gamma^2(1+k) \Gamma(1+u)} e^{-S_{\text{cl}}^{(k)}}, \quad (3)$$

where $u = \alpha_t \beta E_c / 2\pi^2$ and $k_{\pm} = k + \frac{u}{2} \pm \frac{1}{2}\sqrt{4uk + u^2}$. At high temperature this result is of the form of the classical result

$$Z = \sum_{n=-\infty}^{\infty} \exp[-\beta E_c (n - n_{\text{ex}})^2] \quad (4)$$

yet with a renormalized charging energy

$$E_c^* = E_c \{1 - \alpha_t \beta E_c / 2\pi^2 + \mathcal{O}[(\beta E_c)^2]\}.$$

The semiclassical evaluation of the partition function is well-behaved for all α_t if $\beta E_c \ll \pi^2$. However, at low temperatures the “time scale” β is large and the eigenvalues $\lambda_l^{(k)}$ for winding number k are nearly zero for small $l \leq |k|$. Thus, a simple semiclassical approximation with Gaussian fluctuations around the classical paths becomes obsolete. On the other hand, a vanishing eigenvalue indicates free motion of the minimal action trajectory in the direction of the corresponding eigenfunction. Hence, we expect that at low temperatures our system has a family of trajectories of almost the same action.

Let us focus on the case on $k = 1$ where $\varphi(\beta/2) = \varphi(-\beta/2) + 2\pi$ and consider trajectories which gain a phase change of 2π within the imaginary time interval $s \leq \beta$. For given s there is one trajectory with smallest action. This action is found to be almost independent of s as long as $s \gg 1/E_c$. For $s = \beta$ one recovers the classical path $\varphi_{\text{cl}}^{(1)}$. Hence, there is a family of trajectories that have nearly the same action. In contrast to the familiar instanton trajectories determining the low temperature behavior of multi-well systems, the trajectories considered here do not have a well-defined width, rather their action becomes smaller as the width grows. In view of their preference of a sluggish phase change, we shall refer to these trajectories as “sluggons”.

In general, the sluggon trajectories cannot be found analytically. Here we consider the case $\alpha_t \gg 1$, $\beta E_c \gg 1$ which allows for an analytic treatment. In this limit multi-sluggon trajectories with many phase changes of 2π dominate the path integral. The imaginary time interval β may then be decomposed into segments of length s each containing a single phase change of 2π . Hence, a typical sluggon is constant outside a time interval $s \ll \beta$ and moves within the interval s along the path of least action. Now, in the limit considered, the kinetic part of the action may be treated perturbatively, and one finds from the equation of motion (1) that¹⁶

$$\tilde{\varphi}(\tau) = 2 \arctan(\Omega \tau) + \pi + \mathcal{O}(1/\alpha_t, 1/\Omega s), \quad (5)$$

is almost a minimal action path for arbitrary Ω within the interval $1/s \ll \Omega \ll E_c$. The sluggon action reads

$$S[\tilde{\varphi}(\tau)] = \frac{\alpha_t}{2} + \frac{\pi \Omega}{2E_c} + \mathcal{O}(1/\alpha_t, \alpha_t/\Omega s),$$

which is very weakly dependent on Ω as long as $\Omega \ll E_c$.

The eigenvalue problem for fluctuations $\theta(\tau)$ about the sluggon trajectory $\tilde{\varphi}(\tau)$ reads

$$\frac{\ddot{\theta}_n(\tau)}{2E_c} - 2 \int_{-s/2}^{s/2} d\tau' \alpha(\tau - \tau') \cos[\tilde{\varphi}(\tau) - \tilde{\varphi}(\tau')] [\theta_n(\tau) - \theta_n(\tau')] + \Lambda_n \theta_n(\tau) = 0,$$

with the boundary condition $\theta_n(-s/2) = \theta_n(s/2)$. The eigenvalues Λ_n ($n = 1, 2, 3, \dots$) are discrete and doubly degenerate. In the limit $\alpha_t \gg 1$, $s \gg 1/\Omega \gg 1/E_c$, the low-frequency eigenvalues may be determined explicitly. We find

$$\Lambda_n = \frac{\nu_n^2}{2E_c} + \frac{\alpha_t \nu_{n-1}}{2\pi},$$

where $\nu_n = 2\pi n/s$. For $n = 1$, the eigenvalue is nearly zero, and there are two linearly independent zero-modes that may be chosen as

$$\theta_s = \sqrt{\frac{2\Omega}{\pi}} \frac{1}{1 + (\Omega \tau)^2},$$

and

$$\theta_a = \sqrt{\frac{2\Omega}{\pi}} \frac{\Omega \tau}{1 + (\Omega \tau)^2}.$$

These modes are associated with a variation of the sluggon width and the sluggon center, respectively. In the time interval $-s/2 \leq \tau \leq s/2$, the eigenvalues of the fluctuation modes about the trivial trajectory $\tilde{\varphi}(\tau) = 0$ are simply

$$\Lambda_n^0 = \frac{\nu_n^2}{2E_c} + \frac{\alpha_t \nu_n}{2\pi}.$$

The van Vleck determinant for fluctuations about the sluggon with the zero-modes omitted and normalized by the fluctuation determinant about $\tilde{\varphi}(\tau) = 0$ may be evaluated according to

$$K = \Lambda_1^0 \prod_{n=2}^{\infty} \frac{\Lambda_n^0}{\Lambda_n},$$

which gives for $\alpha_t s E_c \gg 1$

$$K = \frac{\alpha_t^2}{2\pi^2} E_c.$$

The contribution to the partition function of paths with winding number k is the sum over all trajectories containing $m + k$ sluggons and m anti-sluggons. Neglecting inter-sluggon interactions, one readily finds

$$Z_k = \sum_{m=0}^{\infty} \frac{(2m+k)!}{(m+k)!m!} \prod_{p=1}^{2m+k} \int_0^{\tau_{2p+1}} d\tau_{2p} \int_0^{\tau_{2p}-\tau_c} d\tau_{2p-1} \frac{2K e^{-\alpha_t/2}}{\tau_{2p} - \tau_{2p-1}}. \quad (6)$$

The integrations over the amplitudes of the two zero-modes of each sluggon have been replaced by integrations over the two “collective coordinates” τ_{2p-1} and τ_{2p} of the sluggon, where $(\tau_{2p-1} + \tau_{2p})/2$ is the sluggon center and $\tau_{2p} - \tau_{2p-1} = \pi/\Omega_p$ the sluggon width. The factor $2/(\tau_{2p} - \tau_{2p-1})$ is the Jacobian resulting from this transformation and τ_c is the smallest sluggon size which is of order $1/E_c$.

To estimate the effect of inter-sluggon interactions, we first note that the two sluggon contribution to Z_2 reads

$$Z_2^{(2)} = 2(\beta K)^2 e^{-\alpha_t} \ln^2(\beta/2\tau_c).$$

This result will be modified by inter-sluggon interactions. For two sluggons with centers at τ_1 and τ_2 , and widths π/Ω_1 and π/Ω_2 , respectively, the asymptotic form of the interaction for large separation is $-\alpha_t/\Omega_1\Omega_2(\tau_1 - \tau_2)^2$. When this is taken into account, we obtain a correction to $Z_2^{(2)}$ proportional to β^2 , hence smaller than $Z_2^{(2)}$ by a factor of order $\ln^{-2}(\beta/\tau_c)$. On the other hand, for small separation the action of two sluggons including interaction is bounded by the action of a 4π -sluggon, which is of order $\beta \ln(\beta/\tau_c)$. Hence, both for small and large separation one finds a negligible correction if β is sufficiently large. Likewise, n non-interacting sluggons give a leading order contribution to Z proportional to $(\beta \ln \beta)^n$ while interactions give only corrections of smaller order for large β . This indicates that the approximations made in deriving (6) are indeed reasonable at low temperature.

Now, from (6) the contribution for winding number k reads

$$Z_k = \sum_{j=k}^{\infty} \frac{[2\beta K e^{-\alpha_t/2} \ln(\beta/j\tau_c)]^j}{\left(\frac{j+k}{2}\right)! \left(\frac{j-k}{2}\right)!}, \quad (7)$$

and the partition function may be written in the form (2) with $C_k = Z_k/Z_0$. This result may be evaluated further for very low temperatures. Let us rewrite (7) as

$$Z_k = \sum_{j=k}^{\infty} e^{f_k(j)}, \quad (8)$$

where

$$f_k(x) = x \ln [2\beta K \exp(-\alpha_t/2) \ln(\beta/\tau_c x)] - \ln [\Gamma(x/2 + k/2 + 1) \Gamma(x/2 - k/2 + 1)].$$

In the limit $\alpha_t \gg 1$, $\beta E_c \gg 1$, this function has a maximum at $x_m = 2\beta K \alpha_t \exp(-\alpha_t/2) [1 - 6 \ln(\alpha_t)/\alpha_t + \mathcal{O}(1/\alpha_t)]$ provided $k \ll x_m$, and the distribution $\exp[f_j(x)]$ becomes Gaussian with a width of order $(2x_m)^{1/2}$. Thus the relevant contributions to (8) result from sluggon configurations with sluggon numbers within $x_m - (2x_m)^{1/2}$ and $x_m + (2x_m)^{1/2}$. The mean distance between sluggons is β/x_m , which is of order $\alpha_t^{-3} \exp(\alpha_t/2)/E_c$. This is much

larger than τ_c for large α_t , but much smaller than β at sufficiently low temperatures. Hence, the conditions under which sluggon trajectories of the form (5) dominate are satisfied.

The sum in (8) may now be evaluated by means of the Euler-Maclaurin formula¹⁷ yielding

$$C_k = \exp \left(-\pi^2 k^2 / \beta E_c^* + \mathcal{O}[k^4 / (\beta E_c^*)^3] \right), \quad (9)$$

where

$$E_c^* / E_c = 2\alpha_t^3 e^{-\alpha_t/2} [1 + \mathcal{O}(\ln(\alpha_t)/\alpha_t)]. \quad (10)$$

For n_{ex} not near 1/2 modulus 1, terms with large winding number are irrelevant and the approximation (9) suffices to determine the partition function, which is found to be of the classical form (4) yet with the charging energy E_c^* defined in (10). Hence the quantum corrections may be absorbed in an effective charging energy. The exponential dependence of E_c^* on α_t is in accordance with the renormalization group analysis⁸. The approach presented here determines the preexponential factor explicitly for large tunneling conductance. The result (10) differs from earlier predictions⁶ for the effective charging energy of single junctions.

In summary we have exploited semiclassical methods to evaluate the partition function of the SEB. We have obtained the leading order quantum corrections to the effective charging energy for arbitrary tunneling conductance α_t at high temperatures. At low temperatures the renormalized charging energy was determined in the limit of a large tunnel conductance. The limit of small tunneling conductance has been treated previously¹³. Combining these results one sees that there remains a lacuna at intermediate α_t where further work is needed. The result (10) can be extended to smaller values of α_t by avoiding the Euler-Maclaurin expansion and evaluating (7) numerically, however, this is not sufficient to close the gap between the available small and large conductance results.

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